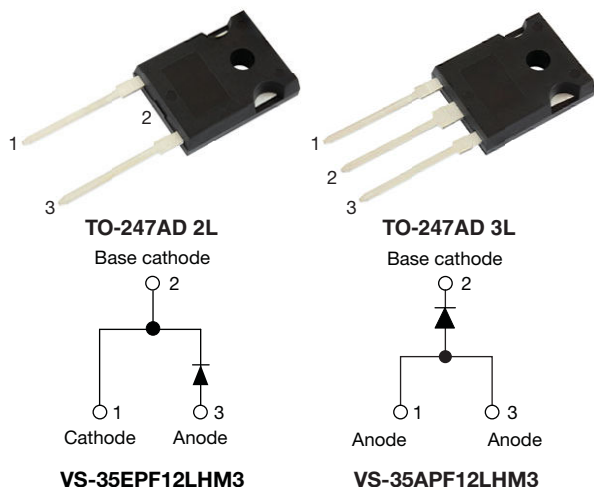


Fast Soft Recovery Rectifier Diode, 35 A



FEATURES

- Very low forward voltage drop
- Glass passivated pellet chip junction
- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage, and short reverse recovery time.

These devices are intended for use in main rectification (single or three phase bridge).

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	35 A
V_R	1200 V
V_F at I_F	1.27 V
I_{FSM}	350 A
t_{rr}	95 ns
T_J max.	150 °C
Package	TO-247AD 2L, TO-247AD 3L
Circuit configuration	Single
Snap factor	0.6

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	35	A
V_{RRM}		1200	V
I_{FSM}		350	A
V_F	15 A, $T_J = 25$ °C	1.27	V
t_{rr}	1 A, 100 A/μs	95	ns
T_J		-40 to +150	°C

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
VS-35EPF12LHM3	1200	1300	6
VS-35APF12LHM3	1200	1300	

**ABSOLUTE MAXIMUM RATINGS**

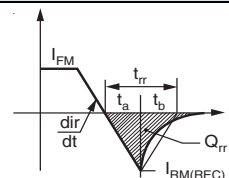
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 102\text{ }^{\circ}\text{C}$, 180° conduction half sine wave	35	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	300	
		10 ms sine pulse, no voltage reapplied	350	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	450	A^2s
		10 ms sine pulse, no voltage reapplied	636	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1\text{ ms to } 10\text{ ms}$, no voltage reapplied	6360	$\text{A}^2\sqrt{\text{s}}$

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	V_{FM}	35 A, $T_J = 25\text{ }^{\circ}\text{C}$	1.47	V
Forward slope resistance	r_t	$T_J = 150\text{ }^{\circ}\text{C}$	10.09	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$		0.992	V
Maximum reverse leakage current	I_{RM}	$T_J = 25\text{ }^{\circ}\text{C}$	0.1	mA
		$T_J = 150\text{ }^{\circ}\text{C}$	6	

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 30 A _{pk} 25 A/ μs 25 °C	450	ns
Reverse recovery current	I_{rr}		6.1	A
Reverse recovery charge	Q_{rr}		2.16	μC
Snap factor	S	Typical	0.6	

**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, unction to case	R _{thJC}	DC operation	0.6	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		40	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased	0.25	
Approximate weight			6	g
			0.21	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-247AD 2L	35EPF12LH	
		Case style TO-247AD 3L	35APF12LH	

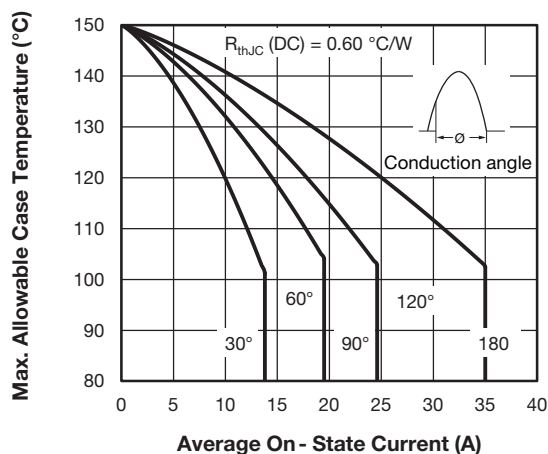


Fig. 1 - Current Rating Characteristics

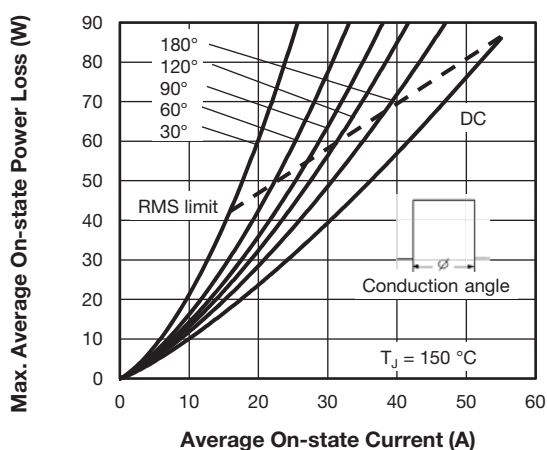


Fig. 4 - Forward Power Loss Characteristics

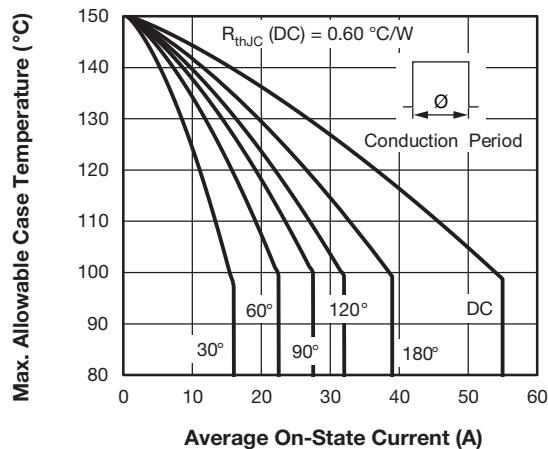


Fig. 2 - Current Rating Characteristics

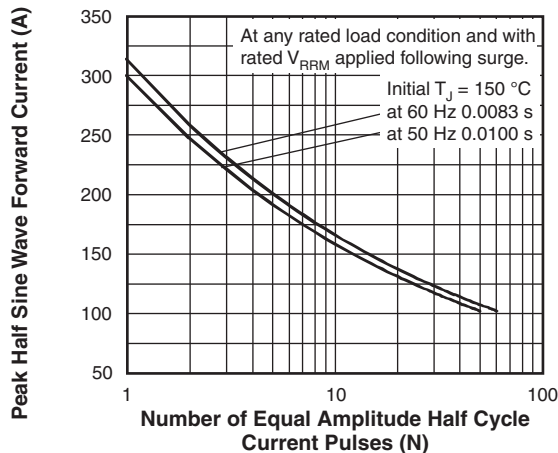


Fig. 5 - Maximum Non-Repetitive Surge Current

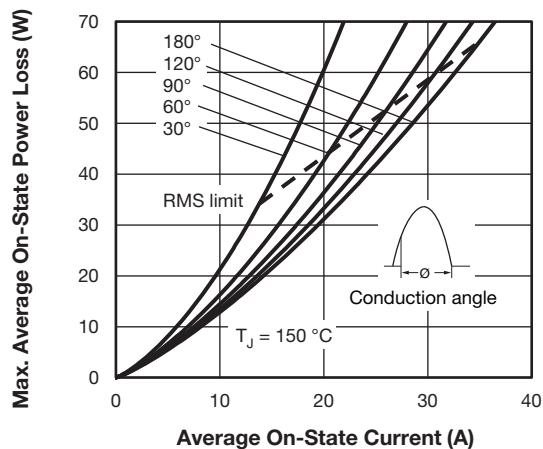


Fig. 3 - Forward Power Loss Characteristics

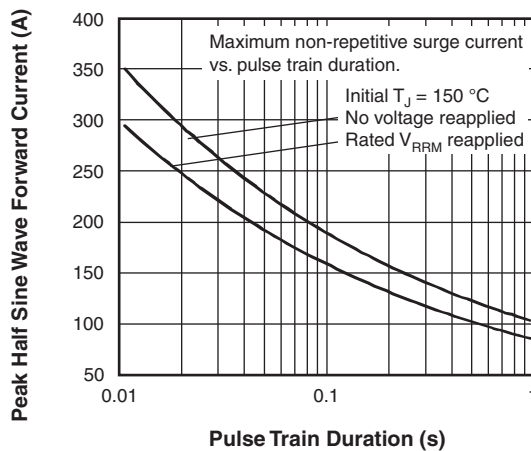


Fig. 6 - Maximum Non-Repetitive Surge Current

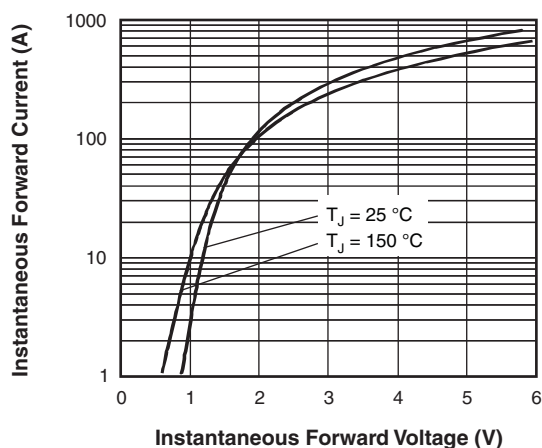


Fig. 7 - Forward Voltage Drop Characteristics

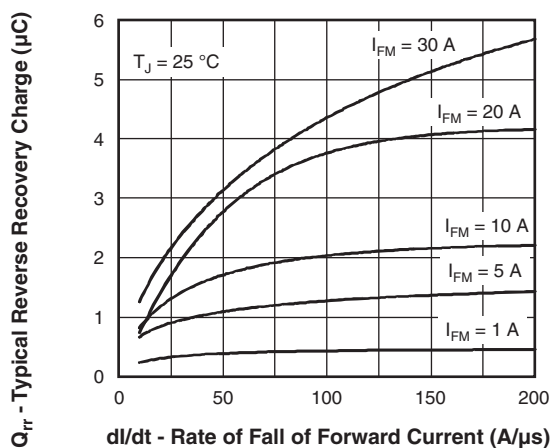


Fig. 10 - Recovery Charge Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

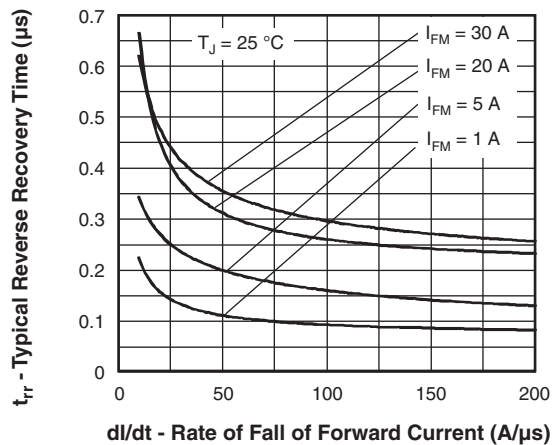


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

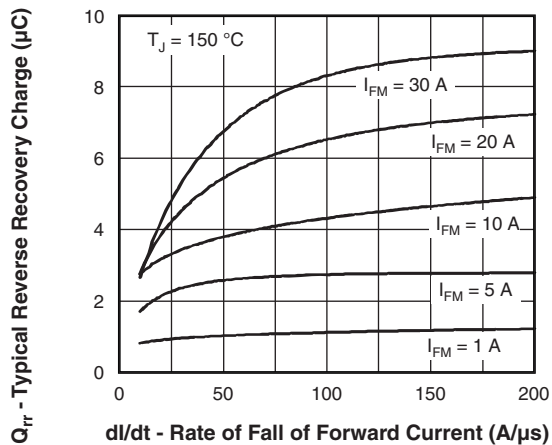


Fig. 11 - Recovery Charge Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

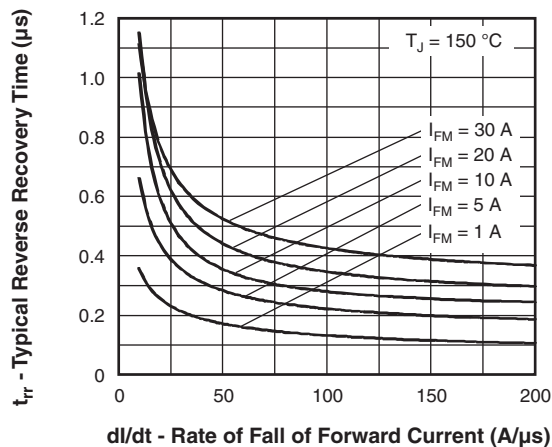


Fig. 9 - Recovery Time Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

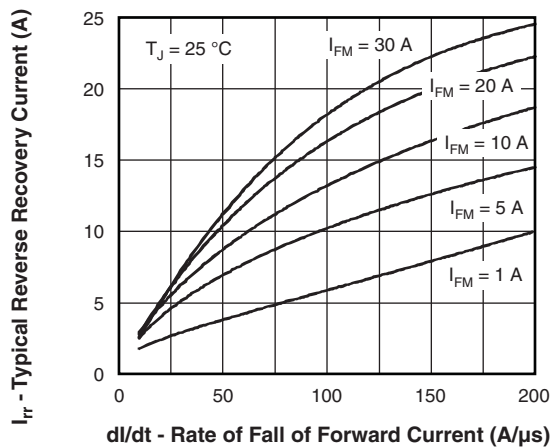


Fig. 12 - Recovery Current Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

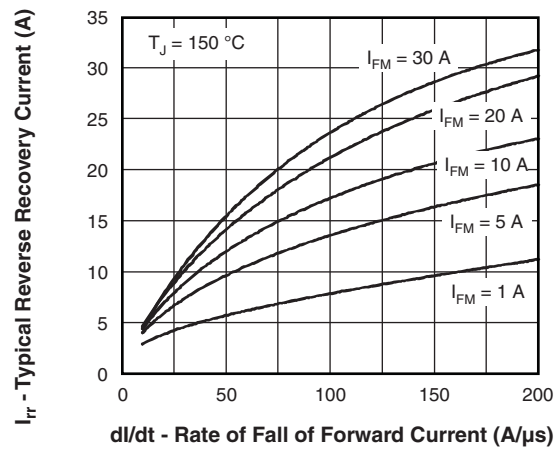


Fig. 13 - Recovery Current Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

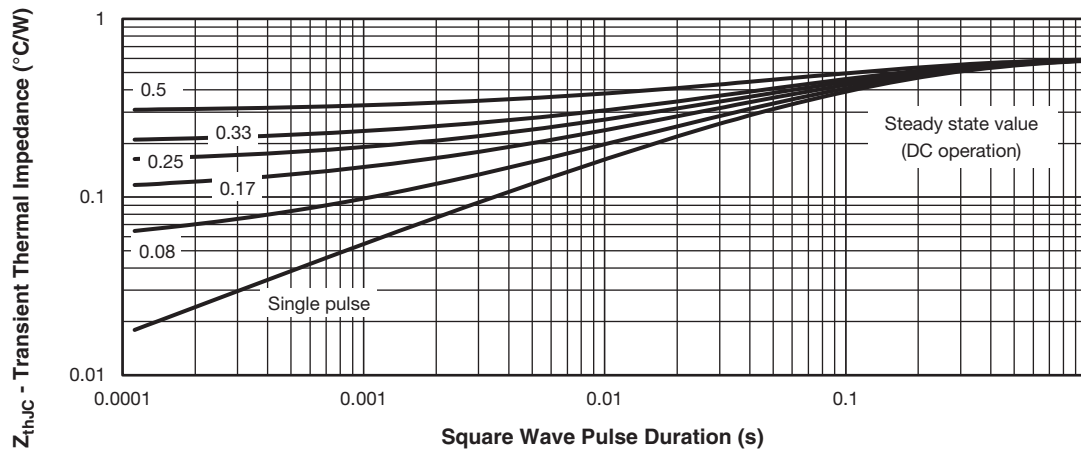


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

**ORDERING INFORMATION TABLE**

Device code	VS-	35	E	P	F	12	L	H	M3
	1	2	3	4	5	6	7	8	9
1	- Vishay Semiconductors product								
2	- Current rating (35 = 35 A)								
3	- Circuit configuration: E = single, 2 pins A = single, 3 pins								
4	- Package: P = TO-247AD								
5	- Type of silicon: F = fast recovery rectifier								
6	- Voltage code x 100 = V_{RRM} 12 = 1200 V								
7	- L = long leads								
8	- H = AEC-Q101 qualified								
9	- Environmental digit: M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free								

ORDERING INFORMATION (Example)

PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-35EPF12LHM3	25	500	Antistatic plastic tubes
VS-35APF12LHM3	25	500	Antistatic plastic tubes

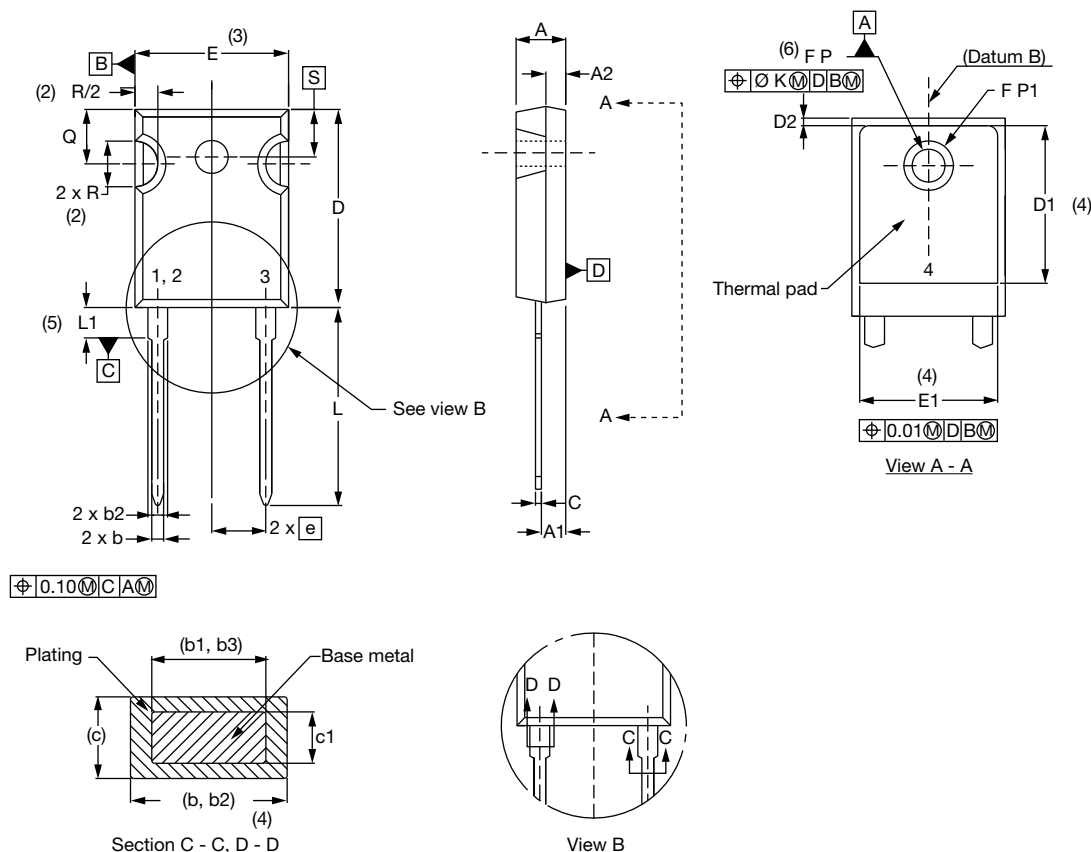
LINKS TO RELATED DOCUMENTS

Dimensions	TO-247AD 2L	www.vishay.com/doc?95536
	TO-247AD 3L	www.vishay.com/doc?95626
Part marking information	TO-247AD 2L	www.vishay.com/doc?95648
	TO-247AD 3L	www.vishay.com/doc?95007



TO-247AD 2L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
c	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
e	5.46 BSC		0.215 BSC		
ϕK	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ϕP	3.56	3.66	0.14	0.144	
$\phi P1$	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

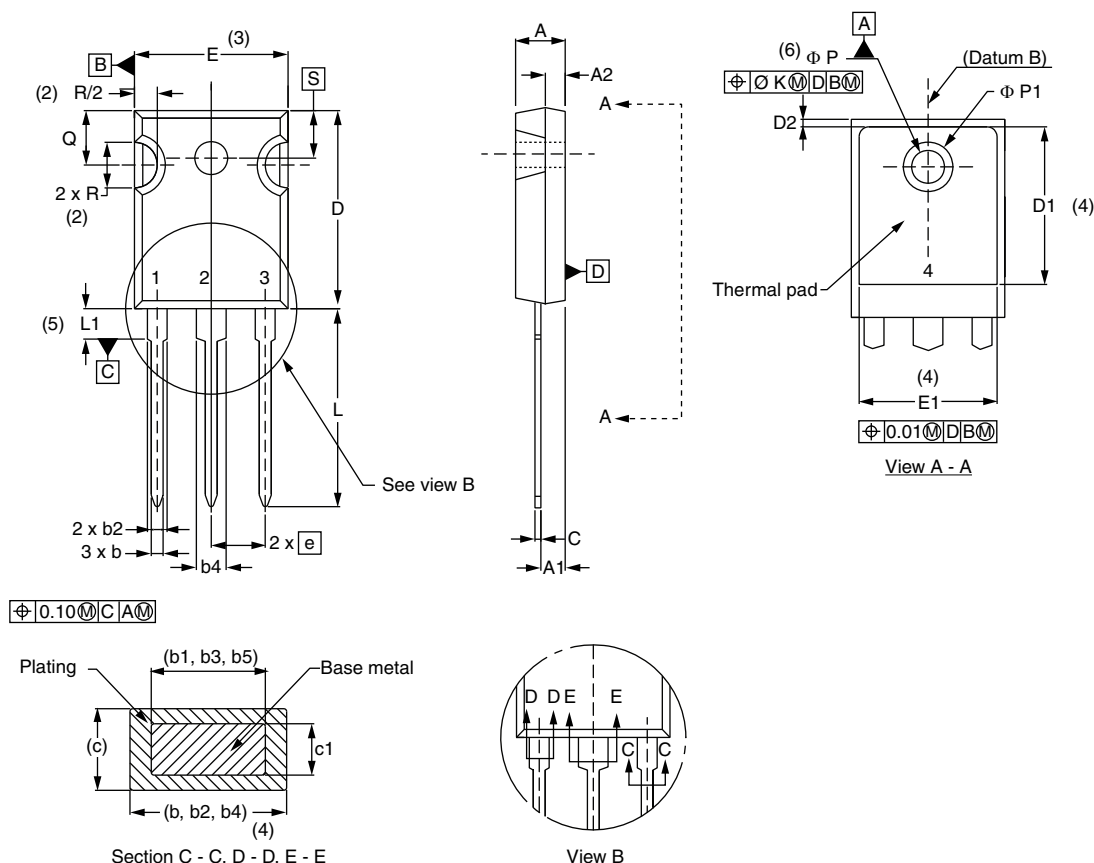
Notes

- Dimensioning and tolerancing per ASME Y14.5M-1994
- Contour of slot optional
- Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- ϕP to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



TO-247AD 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
c	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
e	5.46 BSC		0.215 BSC		
ΦK	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
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Notes

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